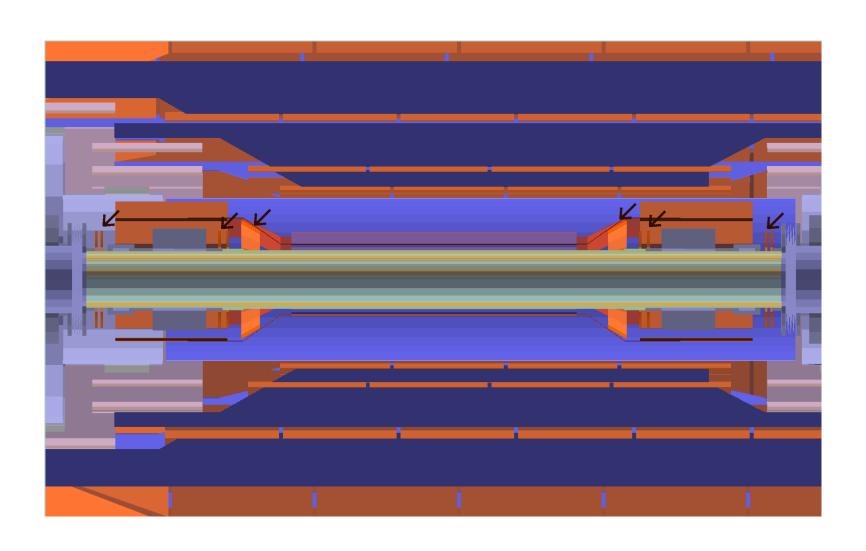
Radiation Monitor: Concepts, Simulation for an Advanced Read Out

R. Cardarelli, A. Di Ciaccio, L. Paolozzi
INFN-Roma Tor Vergata
Super-B Collaboration meeting 20/09/2012
Pisa

Outline

- Location of the beam monitor in the Super-B detector.
- Test of a mono c. v.s. poly c. diamond detector with SiGe amplifier.
- Conclusions and future plans.

Location of the detectors

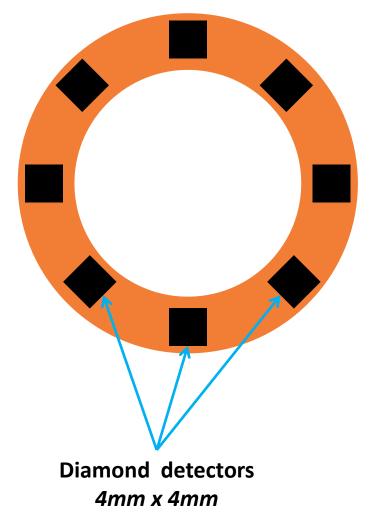


geometry of the detector

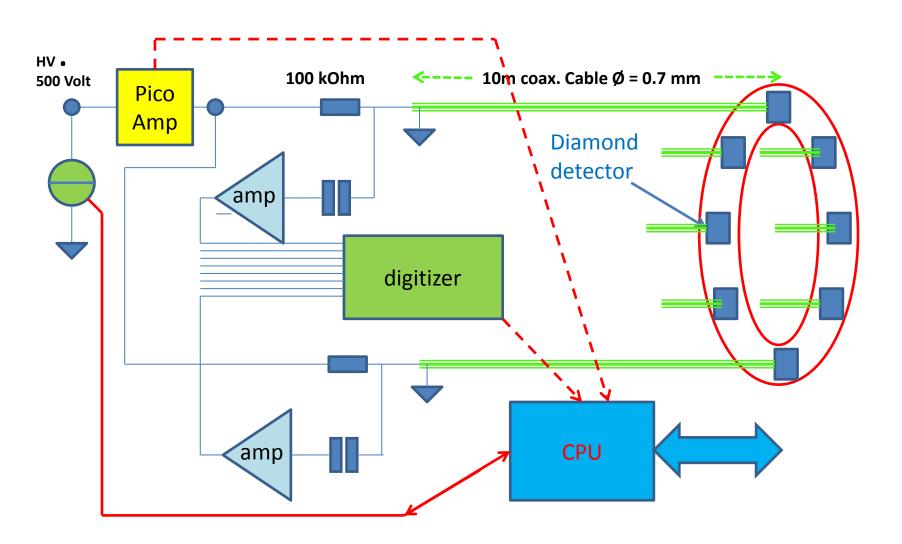
8 diamond detectors for each ring

feature

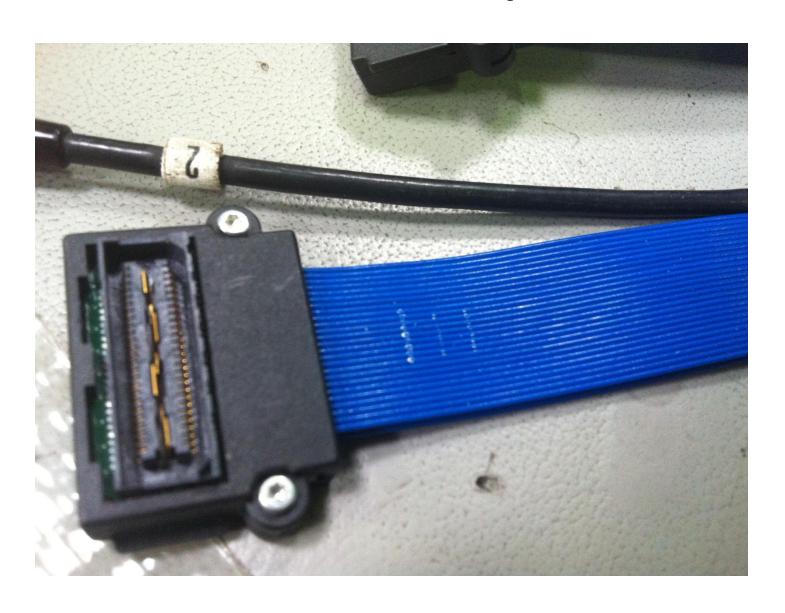
detector size	8 X16 mm ²
leakage current	80x10 ⁻¹⁰ A
Ionization current	6.7x10 ⁻¹⁰ A
hits rate	130KHz
Transit time	20 ns
Integration time	30 ns
Electric resistance	$10^{11}~\Omega$ cm
energy threshold	150KeV



Tentative electronics diagram



Multi-Coaxial Cable $\emptyset = 0.7 \text{ mm}$



Amplifier, AC, (BJT SiGe, BFP740)

Voltage supply

5 Volt

Sensitivity

6 mV/fC

noise

500 e⁻ RMS

Input impedance

50 Ohm

B.W.

30 MHz

Power consumption

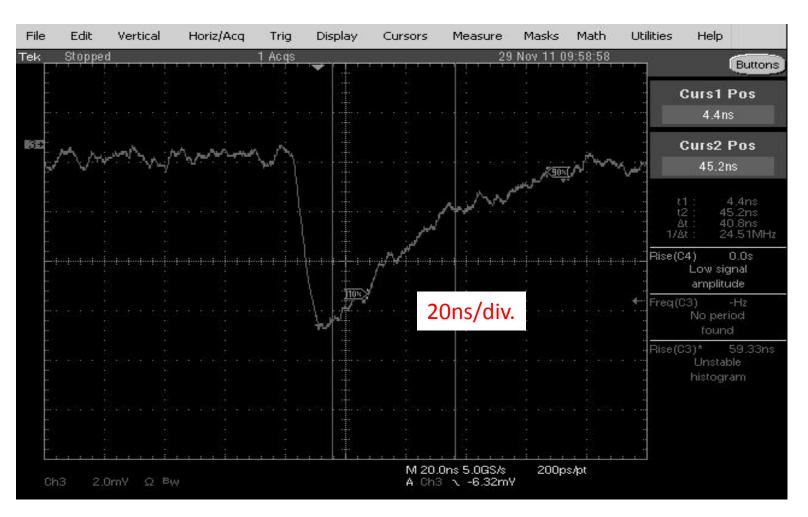
10 mW/ch

Low cost

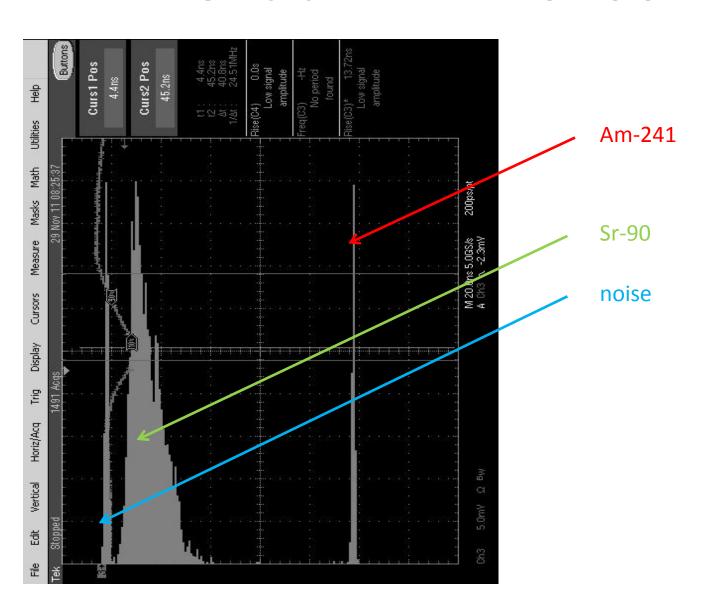
2-3 eur./ch

• Radiation hardness 50 Mrad, 10¹⁵ n cm⁻²

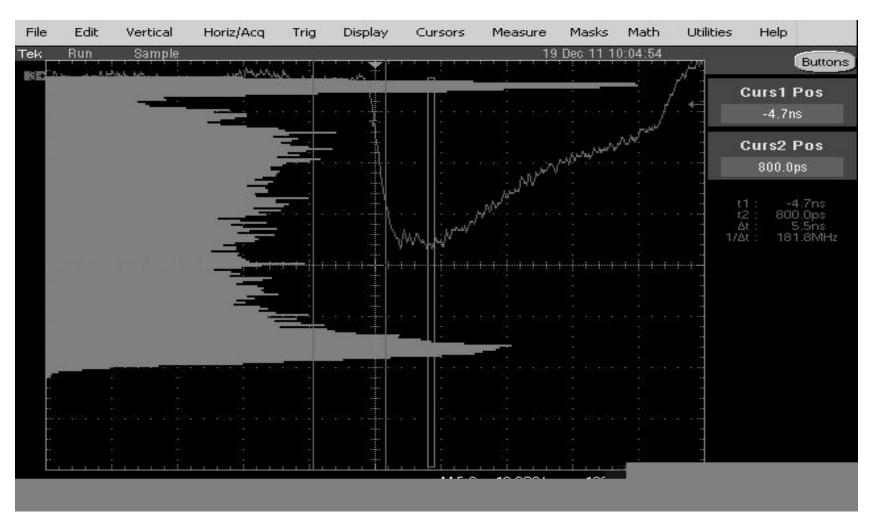
Signal from a minimum ionizing particle



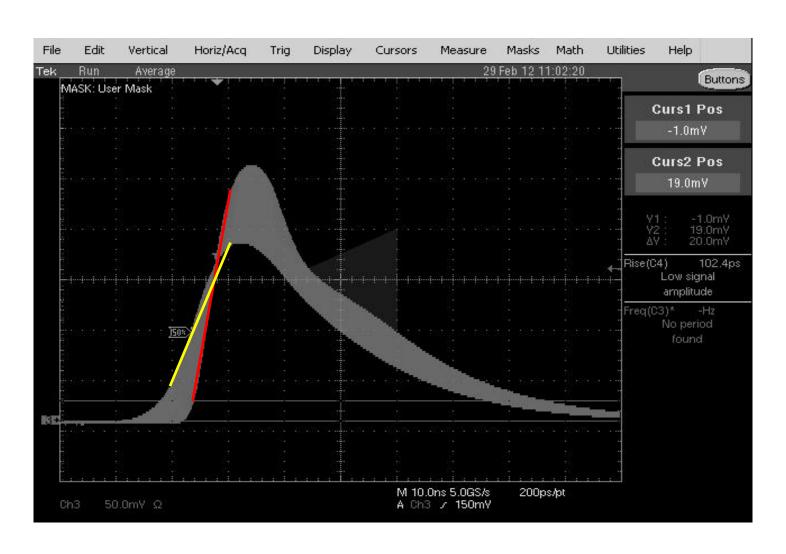
Americium-241 + Sr-90



Polycrystal diamond: alfa source (log scale)



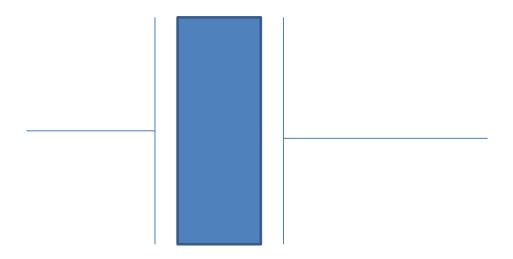
Drift of the monocrystal diamond



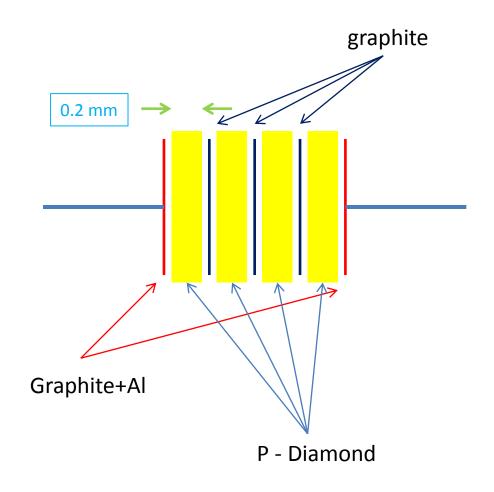
Problems of standard diamont detectors

- Monocrystal is unstable.
- Polycrystal has low charge collection efficiency.

Standard diamond detector



New detector concept



Conclusions

- The background of the detector has been simulated.
- The development of FE electronics is in progress.
- A new structure of diamond detector has been proposed to solve the main problems of the present ones.

Future plans for 2013

- Test at H8 (CERN) with muon beam.
- Test of the new detectors.
- Test of the final layout.
- Developement of a full custom FE electronics in SiGe technology.